



BMS3003

P-Channel Power MOSFET -60V, -78A, 6.5mΩ, TO-220F-3SG

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Features

- ON-resistance $R_{DS(on)1}=5.0m\Omega$ (typ.)
- Input capacitance $C_{iss}=13200pF$ (typ.)
- -4V drive

Specifications

Absolute Maximum Ratings at $T_a=25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Drain to Source Voltage	V_{DSS}		-60	V
Gate to Source Voltage	V_{GSS}		± 20	V
Drain Current (DC)	I_D		-78	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	-312	A
Allowable Power Dissipation	PD		2.0	W
		$T_c=25^\circ C$	40	W
Channel Temperature	T_{ch}		150	$^\circ C$
Storage Temperature	T_{stg}		-55 to +150	$^\circ C$
Avalanche Energy (Single Pulse) *1	EAS		420	mJ
Avalanche Current *2	I_{AV}		-60	A

Note : *1 $V_{DD}=-36V$, $L=100\mu H$, $I_{AV}=-60A$ (Fig.1)

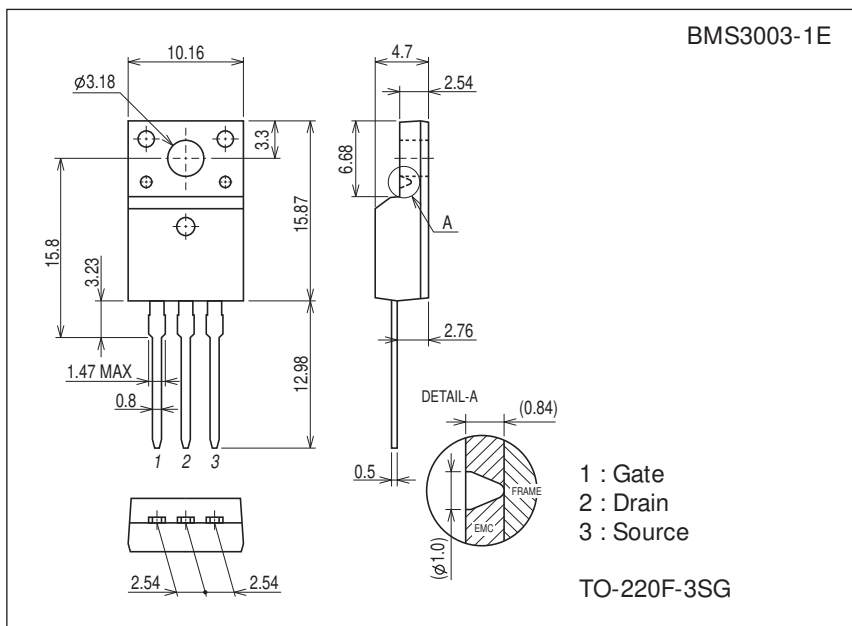
*2 $L \leq 100\mu H$, Single pulse

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Package Dimensions

unit : mm (typ.)

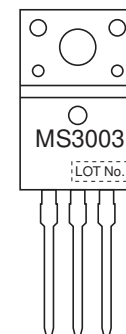
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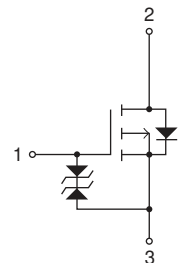
Product & Package Information

- Package : TO-220F-3SG
- JEITA, JEDEC : SC-67
- Minimum Packing Quantity : 50 pcs./tube

Marking



Electrical Connection



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

BMS3003

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-60			V
Zero-Gate Voltage Drain Current	IDSS	VDS=-60V, VGS=0V			-10	μA
Gate to Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	VDS=-10V, ID=-1mA	-1.2		-2.6	V
Forward Transfer Admittance	yfs	VDS=-10V, ID=-39A		130		S
Static Drain to Source On-State Resistance	RDS(on)1	ID=-39A, VGS=-10V		5.0	6.5	mΩ
	RDS(on)2	ID=-39A, VGS=-4V		6.5	9.0	mΩ
Input Capacitance	Ciss	VDS=-20V, f=1MHz		13200		pF
Output Capacitance	Coss			1300		pF
Reverse Transfer Capacitance	Crss			950		pF
Turn-ON Delay Time	td(on)	See Fig.2		90		ns
Rise Time	tr			360		ns
Turn-OFF Delay Time	td(off)			1200		ns
Fall Time	tf			680		ns
Total Gate Charge	Qg			285		nC
Gate to Source Charge	Qgs	VDS=-36V, VGS=-10V, ID=-78A		35		nC
Gate to Drain "Miller" Charge	Qgd			70		nC
Diode Forward Voltage	VSD		IS=-78A, VGS=0V		-0.95	-1.5
Reverse Recovery Time	trr	See Fig.3		150		ns
Reverse Recovery Charge	Qrr	IS=-78A, VGS=0V, di/dt=-100A/μs		470		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Fig.1 Unclamped Inductive Switching Test Circuit

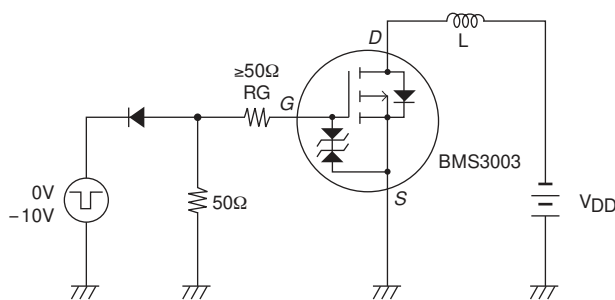


Fig.2 Switching Time Test Circuit

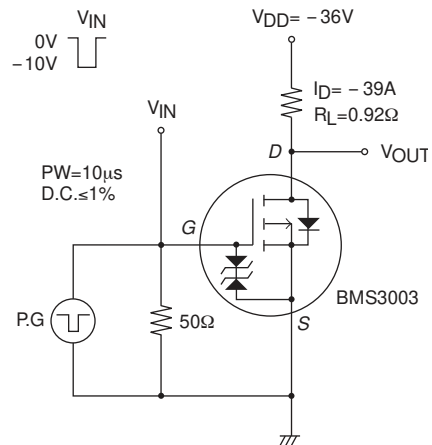
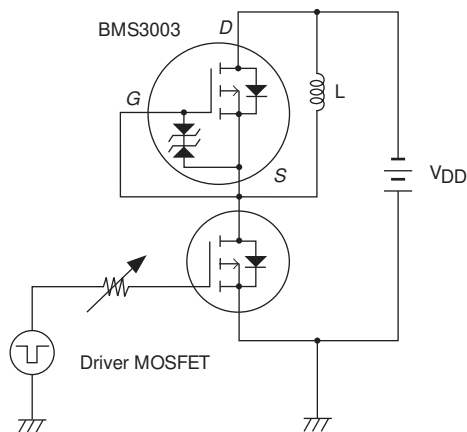


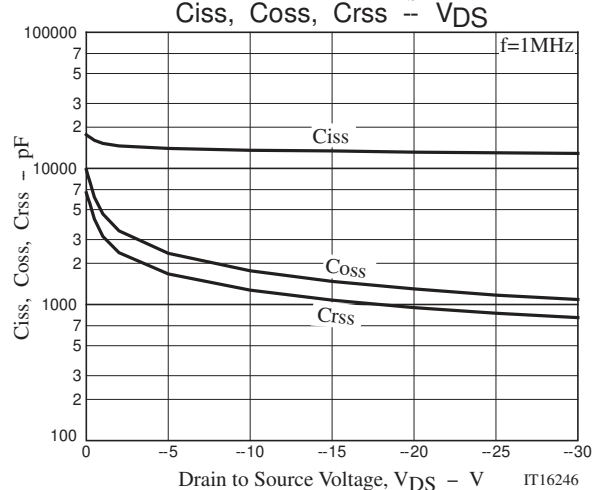
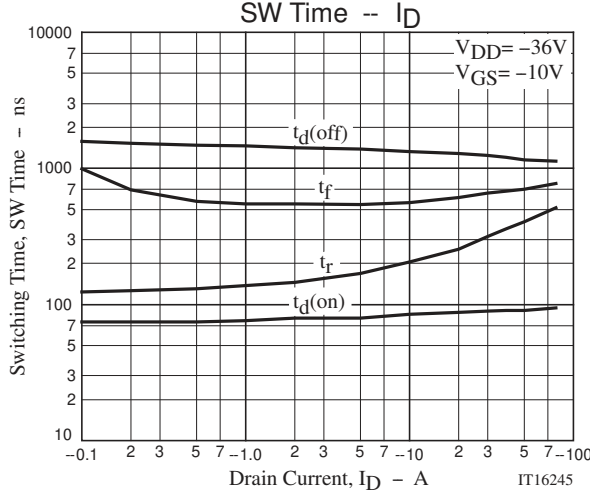
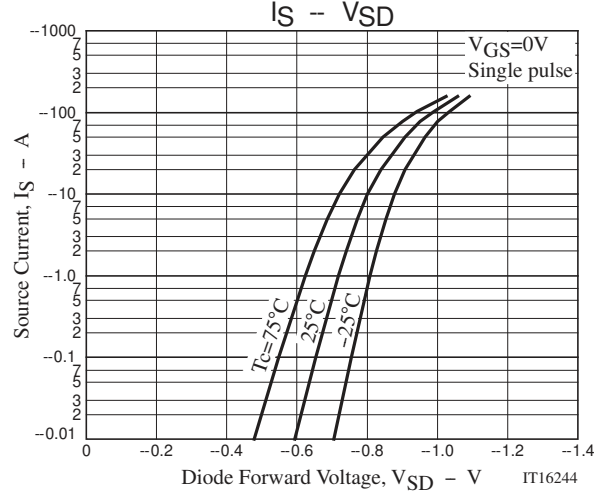
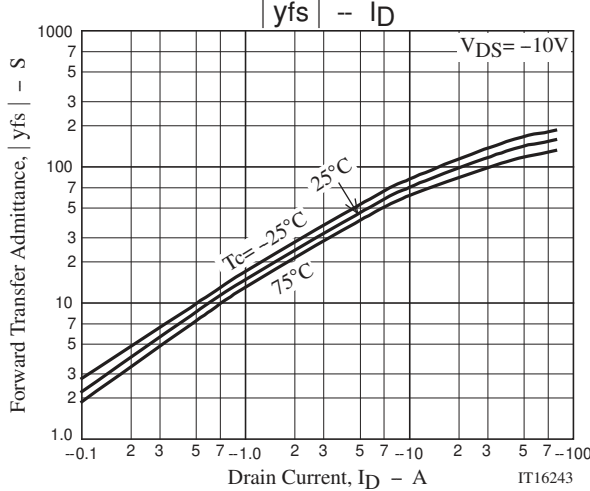
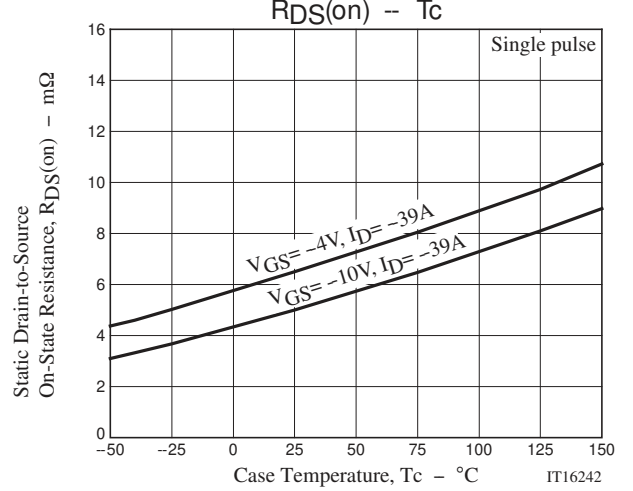
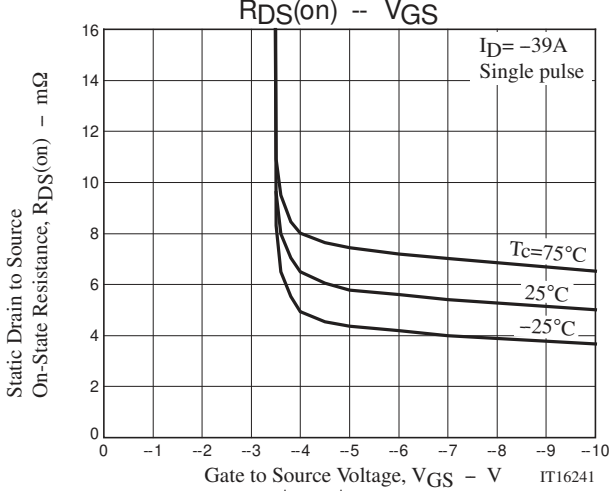
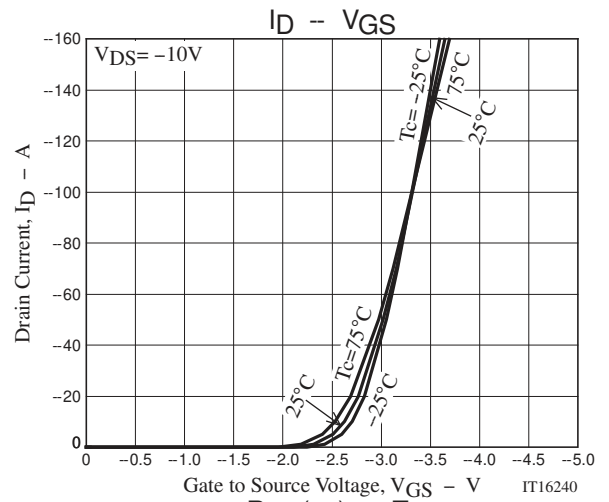
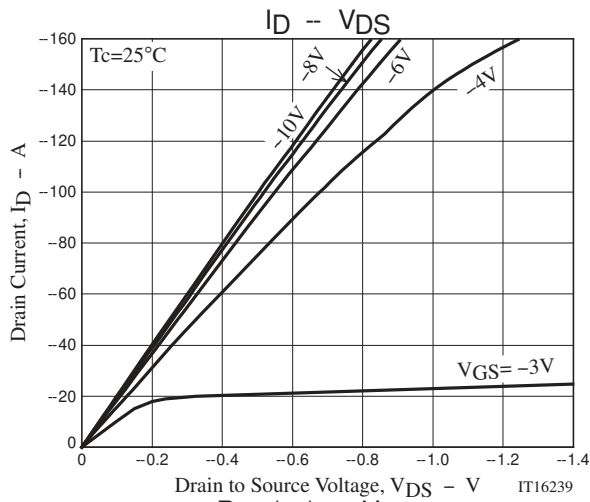
Fig.3 Reverse Recovery Time Test Circuit



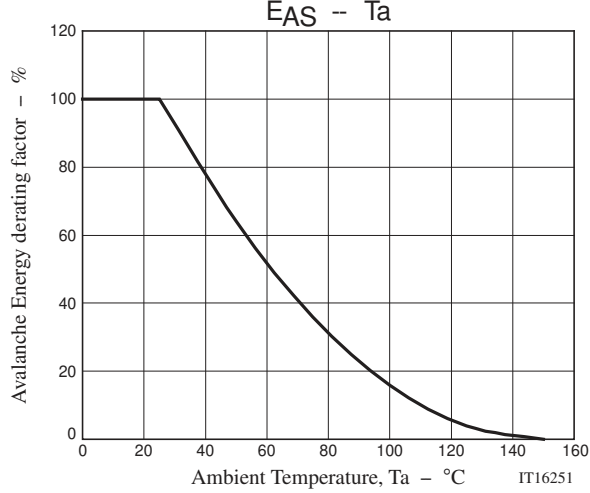
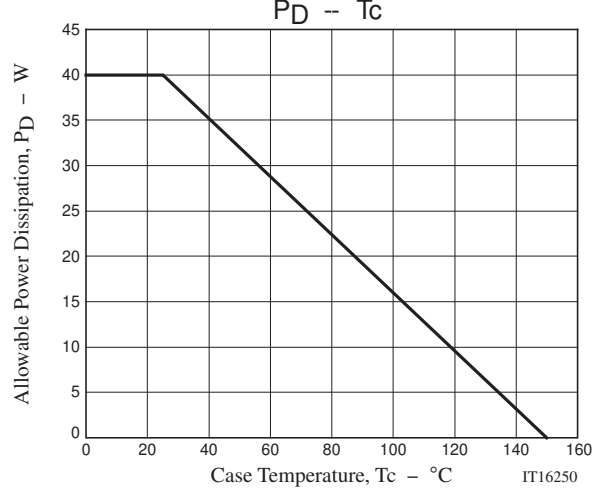
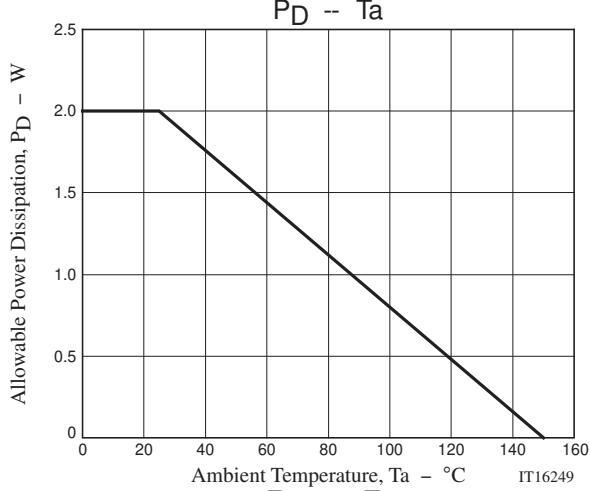
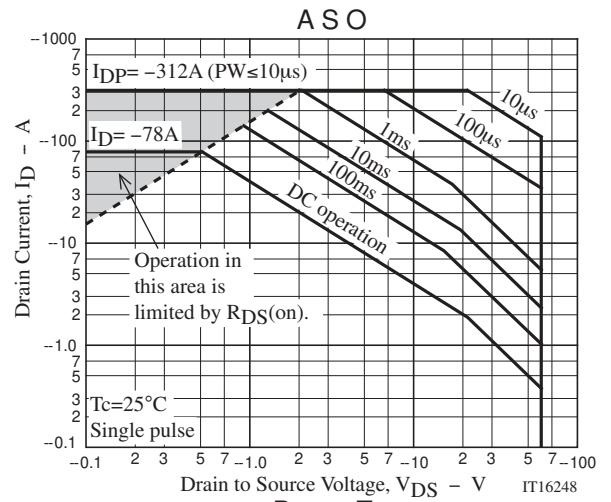
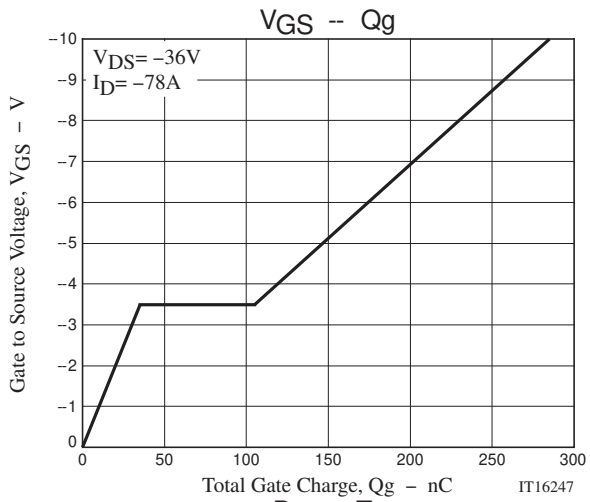
Ordering Information

Device	Package	Shipping	memo
BMS3003-1E	TO-220F-3SG	50pcs./tube	Pb Free

BMS3003



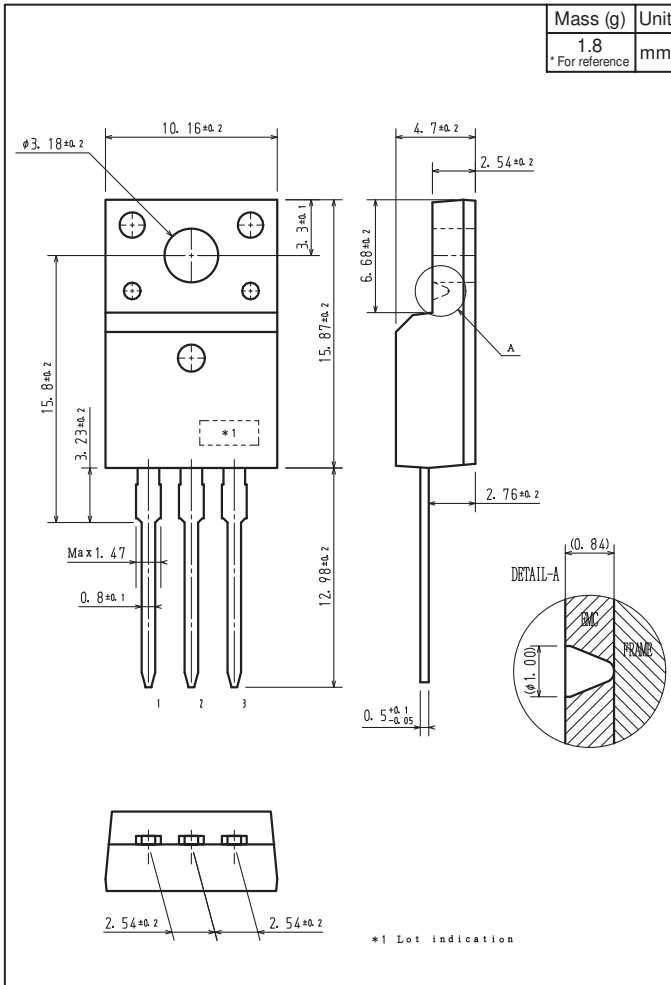
BMS3003



BMS3003

Outline Drawing

BMS3003-1E



Note on usage : Since the BMS3003 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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